



# Ruttonsha International Rectifier Ltd.

## SILICON CONTROLLED RECTIFIERS

### High Power Thyristor Hockey Puk Version K-PUK Series 2000PK

Types : 2000 PK 180

#### FEATURES

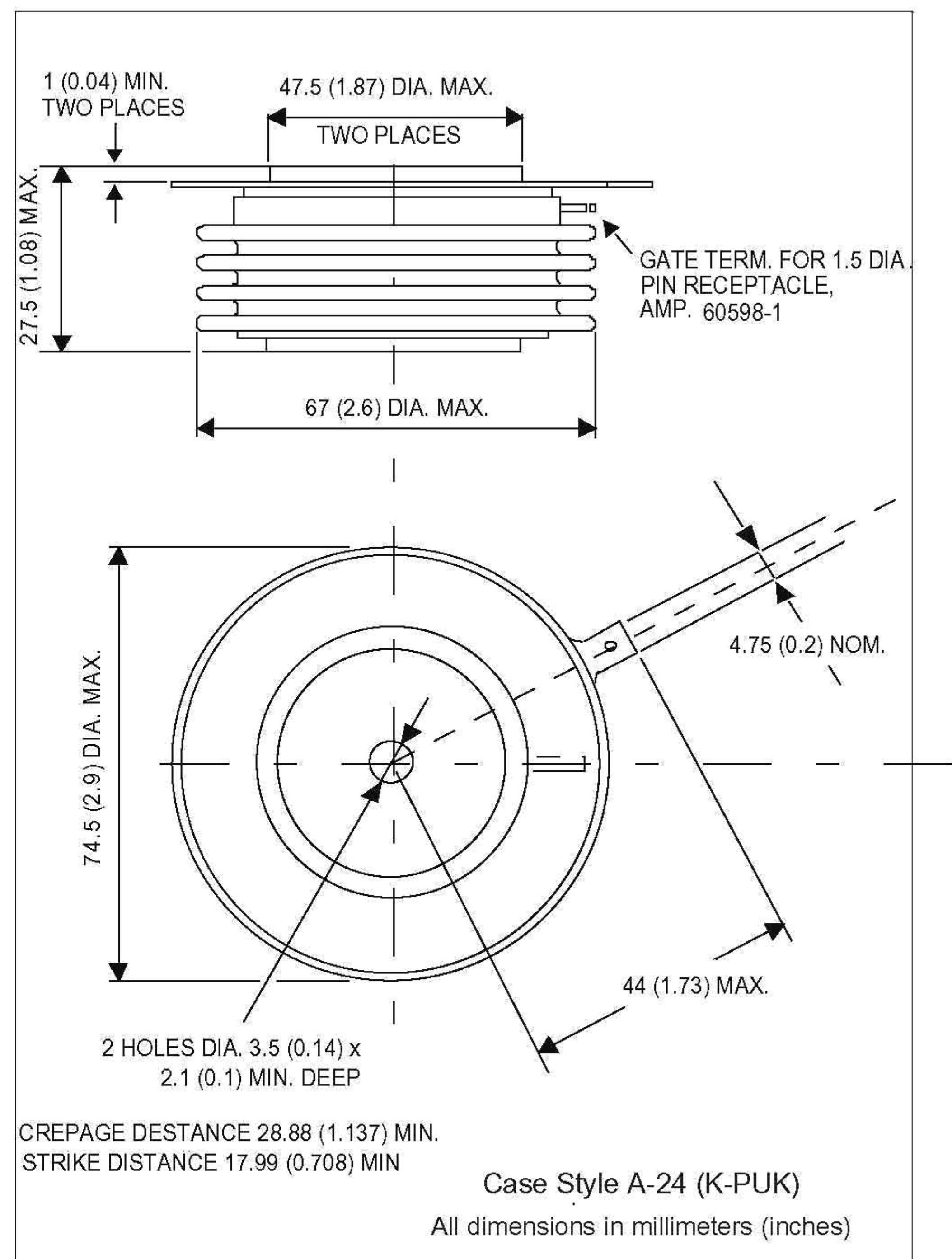
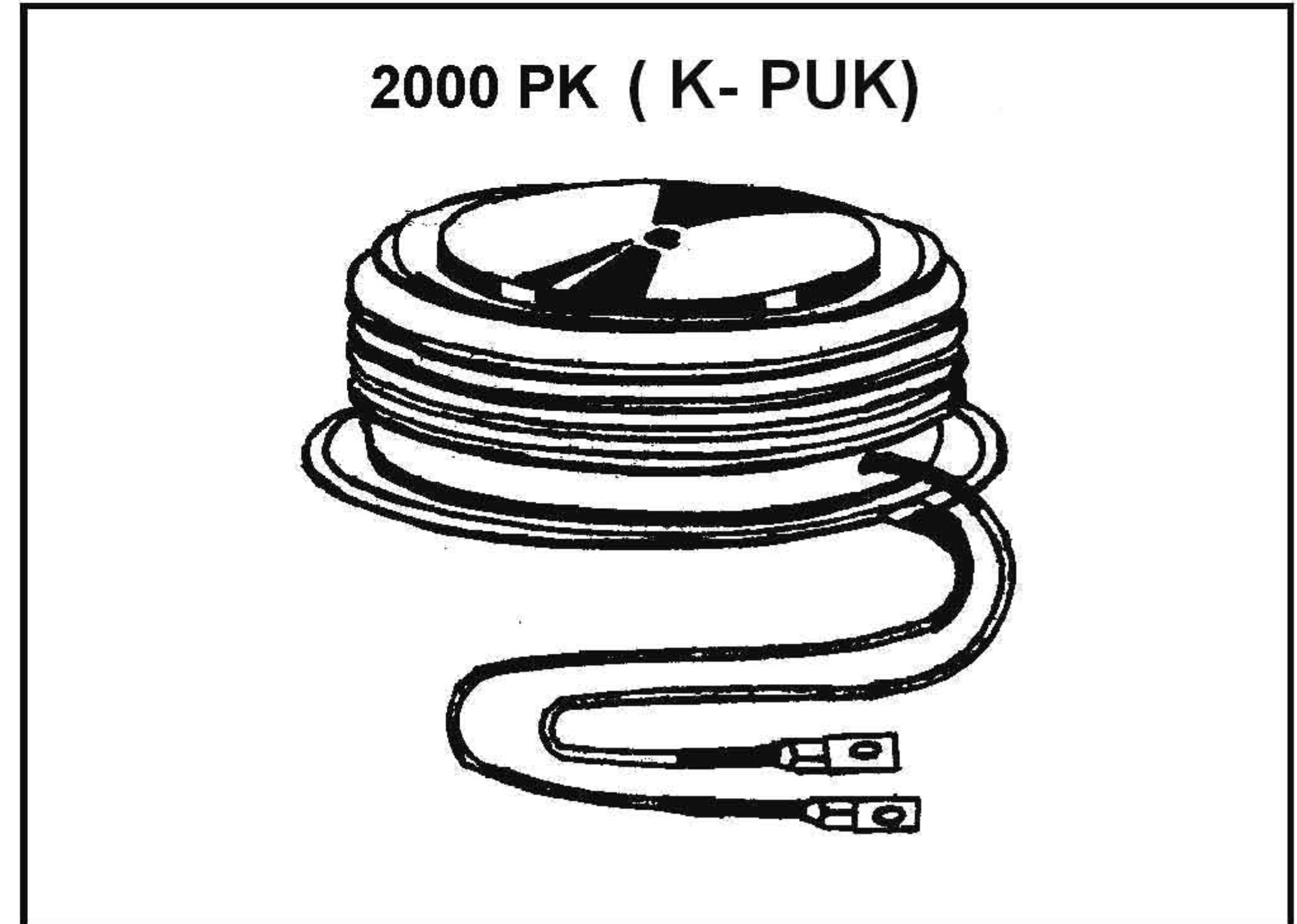
- ❖ Center amplifying gate.
- ❖ Metal case with ceramic insulator
- ❖ High profile hockey - puk.

#### TYPICAL APPLICATIONS

- ❖ DC motor control (e.g. for machine tools).
- ❖ Controlled rectifiers (e.g. for battery charging, Uninterrupted Power Supply).
- ❖ AC controllers (e.g. for temperature control, lights control).

#### Major Ratings and Characteristics

Parameter	2000PK	Units
$I_{T(AV)}$	2000	A
@ $T_{hs}$	58	°C
$I_{T(RMS)}$	3140	A
@ $T_{hs}$	58	°C
$I_{TSM}$	36	KA
$I^2t$	6480	KA <sup>2</sup> s
$V_{DRM}/V_{RRM}$	400 to 1800	V
$t_q$ typical	200	μs
$T_J$	125	°C



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## ELECTRICAL SPECIFICATIONS

## 2000 PK Series

### Voltage Ratings

Type number	Voltage Code	$V_{DRM}/V_{RRM}$ , max repetitive peak and off-state voltage V	$V_{RSM}$ , maximum non-repetitive peak voltage V	$I_{DRM}/I_{RRM}$ max. @ $T_J = T_{J\max}$ mA
2000PK	040	400	500	100
	080	800	900	
	120	1200	1300	
	160	1600	1700	
	180	1800	1900	

### On - state Conduction

Parameter	2000PK	Units	Conditions
$I_{T(AV)}$ Max. average on-state current @ Heatsink temperature	2000	A	180° conduction, half sine wave double side cooled
	58	°C	
$I_{T(RMS)}$ Max RMS on-state current	3140	A	DC @ 58°C heatsink temperature double side cooled
$I_{TSM}$ Max. peak, one-cycle non-repetitive surge current	36	KA	$t = 10 \text{ ms}$
$I^2t$ Maximum $I^2t$ for fusing	6480	KA <sup>2</sup> s	$t = 10 \text{ ms}$  Sinusoidal half wave, Initial $T_J = T_{J\max}$ .
$V_{T(TO)}$ Threshold voltage	0.82	V	$T_J = T_{J\max}$
$r_t$ On-state slope resistance	0.127	$\text{m}\Omega$	$T_J = T_{J\max}$
$V_{TM}$ Max. on state voltage	1.4	V	$I_{PK} = 3000A, T_J = T_{J\max}, t_P = 10 \text{ ms}$ sine pulse
$I_H$ Maximum holding current	150	mA	$T_J = 25^\circ\text{C}$ , anode supply 12 V resistive load
$I_L$ Typical latching current	500	mA	$T_J = 25^\circ\text{C}$ , anode supply 12 V resistive load

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## 2000 PK Series

### Switching

Parameter	2000PK	Units	Conditions
di/dt Max. non-repetitive rate of rise of turned-on current	150	A/ $\mu$ s	Gate drive 20V, $20\Omega$ , $t_r \leq 1\mu$ s $T_J = T_J$ max. anode voltage $\leq 80\%$ $V_{DRM}$
$t_q$ Typical turn-off time	200	$\mu$ s	

### Blocking

Parameter	2000PK	Units	Conditions
dv/dt Maximum critical rate of rise of off-state voltage	500	V/ $\mu$ s	$T_J = T_J$ max. linear to 60% rated $V_{DRM}$
$I_{RRM}$ Max. peak reverse and off-state leakage current	100	mA	$T_J = T_J$ max. rated $V_{DRM}$ / $V_{RRM}$ applied

### Triggering

Parameter	2000PK	Units	Conditions
$P_{GM}$ Maximum peak gate power	16	W	$T_J = T_J$ max., $t_p \leq 5$ ms
$P_{G(AV)}$ Maximum average gate power	3.0		$T_J = T_J$ max., $f = 50\text{Hz}$ , $d\% = 50$
$I_{GM}$ Max. peak positive gate current	3.0	A	$T_J = T_J$ max., $t_p \leq 5$ ms
$+V_{GM}$ Maximum peak positive gate voltage	20	V	$T_J = T_J$ max., $t_p \leq 5$ ms
$-V_{GM}$ Maximum peak negative gate voltage	5.0		
$I_{GT}$ DC gate current required to trigger	TYP.	MAX.	$T_J = 25^\circ\text{C}$ Max.required gate trigger/ current/voltage are the lowest value which will trigger all units 12 V anode-to-cathode applied
	100	200	
$V_{GT}$ DC gate voltage required to trigger	1.1	3.0	$T_J = 25^\circ\text{C}$
$I_{GD}$ DC gate current not to trigger	10	mA	$T_J = T_J$ max. Max. gate current/voltage not to trigger is the max. value which will not trigger any unit with rated $V_{DRM}$ anode-to-cathode applied
$V_{GD}$ DC gate voltage not to trigger	0.25	V	

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### Thermal and Mechanical Specifications

Parameter	2000PK	Units	Conditions
$T_J$	Max.operating temperature range	125	°C
$T_{stg}$	Max.storage temperature range	150	
$R_{th (J-C)}$	Max. thermal resistance, junction to case	0.015	K/W DC operation double side cooled
$R_{th (C-HK)}$	Max. thermal resistance, case to heatsink	0.005	K/W
F	Mounting force, $\pm 10\%$	24.5	KN
wt	Approximate weight	425	g
	Case style	K-PUK	See Outline Table

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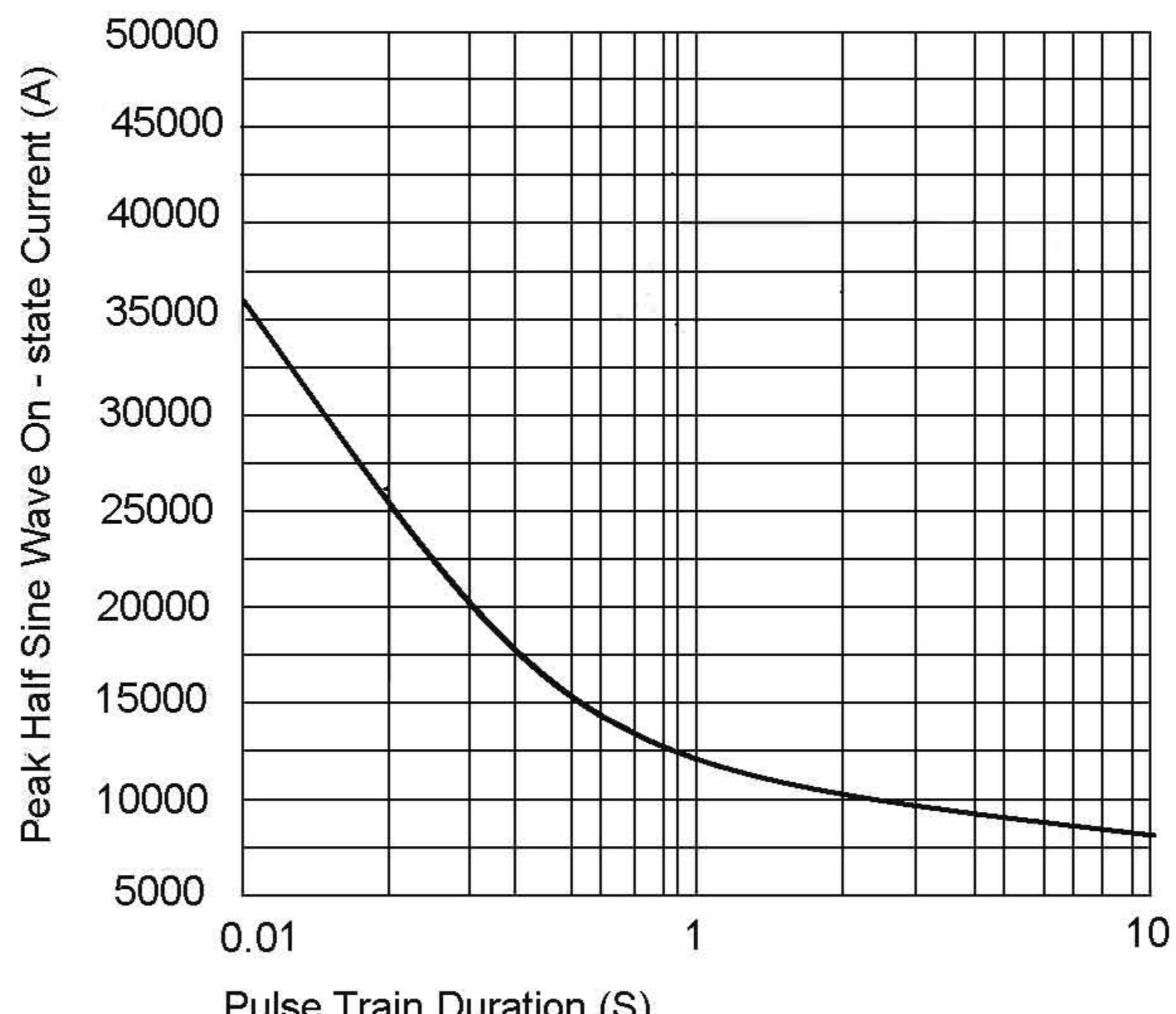


Fig. 1 - Maximum Non - Repetitive Surge Current

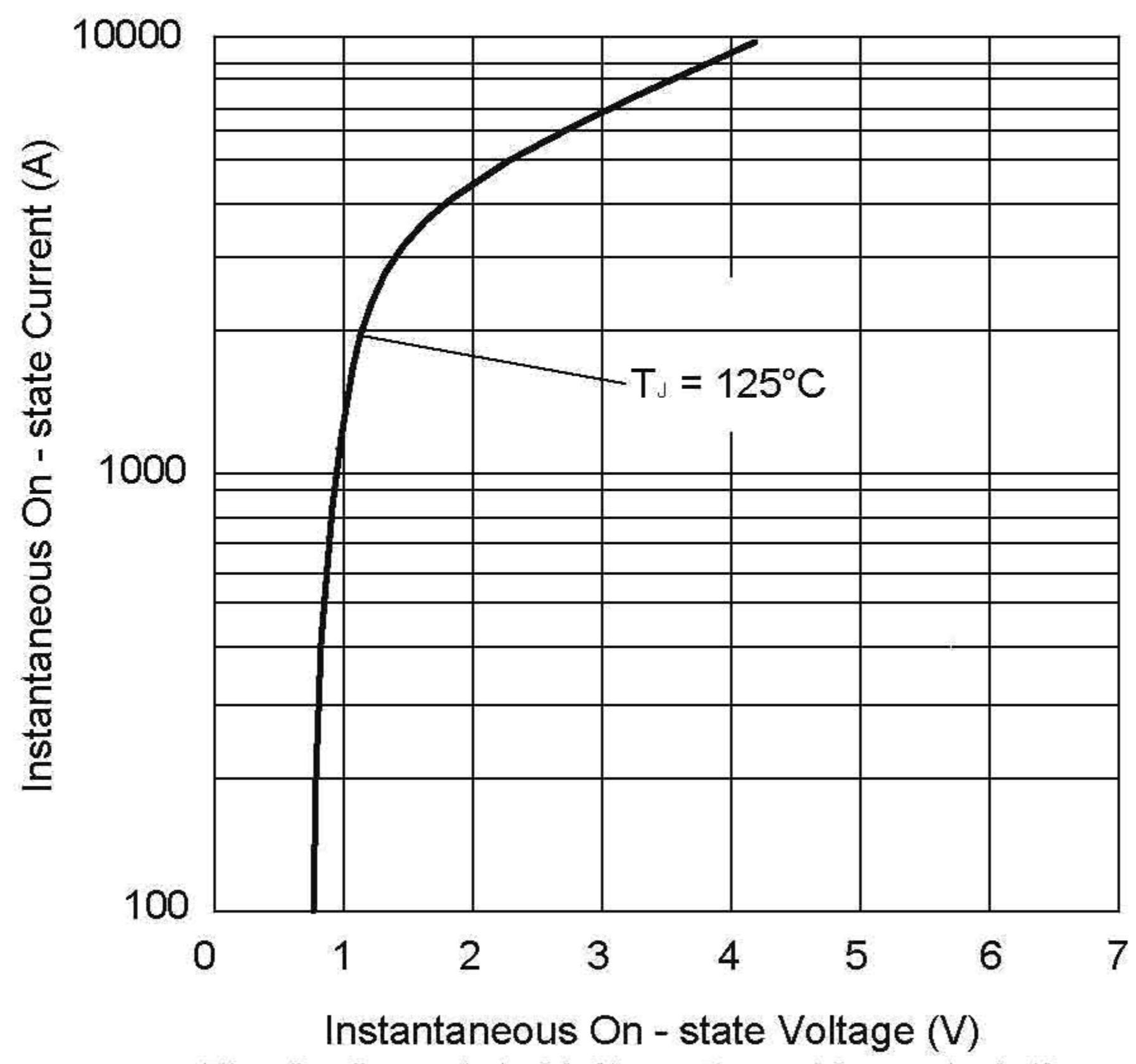


Fig. 2 - On - state Voltage Drop Characteristics

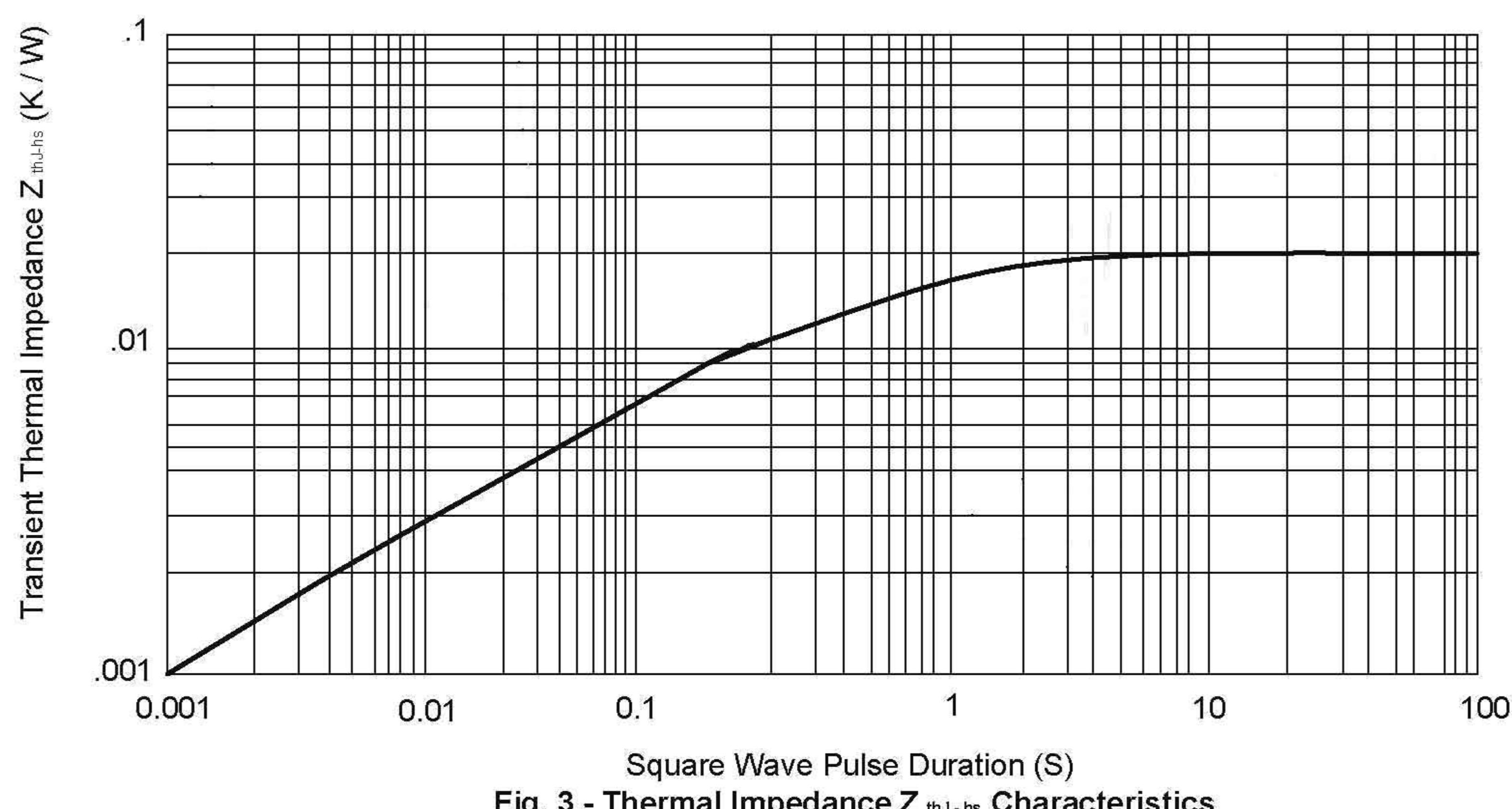


Fig. 3 - Thermal Impedance  $Z_{thJ-hs}$  Characteristics